Docket No. 150.00800102

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit: 1756 Applicant(s): Brian A. Vaartstra Examiner: N. Barreca Serial No .: 09/651,702 Confirmation No.: 2471 August 30, 2000 Filed:

SUPERCRITICAL COMPOSITIONS FOR REMOVAL OF ORGANIC MATERIAL For:

AND METHODS OF USING SAME

## AMENDMENT AND RESPONSE

Assistant Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action mailed March 20, 2003, please amend the aboveidentified application as follows:

## In the Specification

Please replace the paragraph beginning at page 25, line 5 (i.e., Abstract of the Disclosure), with the following rewritten paragraph. Per 37 C.F.R. §1.121, this paragraph is also shown in Appendix A with notations to indicate the changes made.

A method for removing organic material in the fabrication of structures includes providing a substrate assembly having an exposed organic material and removing at least a portion of the exposed organic material using a composition including sulfur trioxide (SO<sub>3</sub>) in a supercritical state. For example, the exposed organic material may be selected from the group of resist material, photoresist residue, UV-hardened resist, X-ray hardened resist, Sarbon-fluorine containing polymers, plasma etch residues, and organic impurities from other grocesses. Further, organic material removal compositions for performing such methods are provided/--

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